MIC4604/4605

1.5A Dual Open-Drain MOSFET Driver

Preliminary Information

General Description

The MIC4604 and MIC4605 are BiCMOS/DMOS buffer-drivers constructed with complementary MOS outputs, where the drains of the final output totem pole have been left disconnected so individual connections can be made to the pull-up and pull down sections of the output. This allows the insertion of individual drain-current-limiting resistors in the pull up and pull down sections of the output, thus allowing the user to define the rates of rise and fall desired for a capacitive load, or a reduced output swing if driving a resistive load, or to limit base current when driving a bipolar transistor. Minimum rise and fall times, with no resistors, will be less than 20ns for a 1000pF load. There is no upper limit.

These devices are rugged due to extra steps taken to protect them from failures. A modern Bipolar/CMOS/DMOS process guarantees freedom from latchup. Proprietary circuits allow the input to swing negative as much as 5V without damaging the part.

For driving MOSFETs in motor-control applications, where slow on/fast off operation is desired, these devices are superior to the previously used technique of adding a diode resistor combination between the driver output and the MOSFET, because they allow accurate control of turn-ON, while maintaining fast turn-OFF and maximum noise immunity for an OFF device.

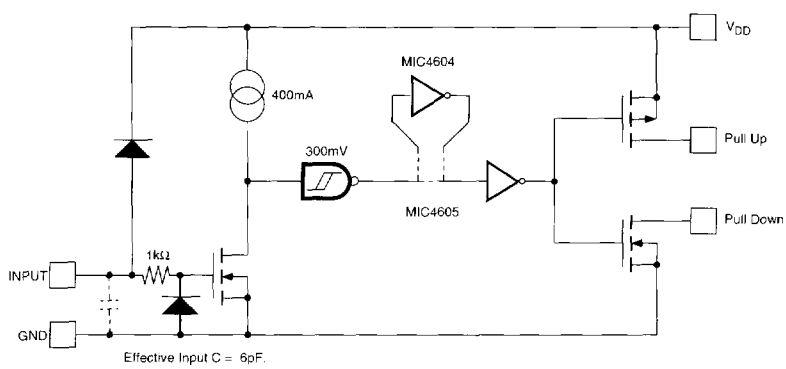
Features

- Independently Programmable Rise and Fall Times
- Low Output Impedance ..... 6Ω Typ
- High Speed t_R, t_F ..... <30ns with 1000pF Load
- Short Delay Times ..... <25ns typ
- Wide Operating Range ..... 4.5V to 18V
- Latch-Up Protection: Fully Isolated Process is Inherently Immune to to Any Latch-up
- Input Withstands Negative Swings to –5V
- ESD Protected 2kV

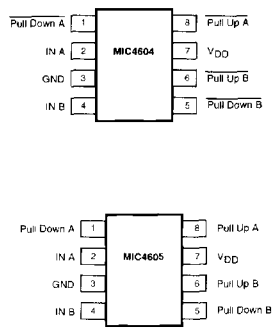
Applications

- Motor Controls
- Self-Commutating MOSFET Bridge Driver
- Driving Bipolar Transistors
- Drive for Nonoverlapping Totem Poles
- Level Shifters
- Power Management

Functional Diagram



Pin Configuration



When used to drive bipolar transistors, this driver maintains high speeds and allows insertion of a base current-limiting resistor, and also provides a separate half-output for fast turn-off. By proper positioning of the resistor, either NPN or PNP transistors can be driven.

These drivers, since they eliminate shoot-through currents in the output stage, require significantly less power at higher frequencies. This can be helpful in meeting low-power budgets.

Due to independent drains, this device can also be used as an open-drain buffer/driver where both drains are available in one device, thus minimizing chip count. An unused pull-down should be returned to the ground; an unused pull-up should be returned to V_{DD}. This is to prevent static damage. Alternatively, in situations requiring greater current-carrying capacity, multiple MIC4604 or MIC4605s may be paralleled.

The MIC4604/4605 will not latch under any conditions within its power and voltage ratings. It is not subject to damage when up to 5V of noise spiking of either polarity occurs on the ground pin. It can accept, without damage or logic upset, up to 1.5 amps of reverse current (of either polarity) being forced back into the outputs.

Absolute Maximum Ratings (Note 1)

Supply Voltage ..... +22V
Maximum Chip Temperature ..... +150°C
Storage Temperature Range ..... –65°C to +150°C
Lead Temperature (Soldering, 10 sec) ..... +300°C
Package Thermal Resistance
CerDIP θ_{J-A} ..... 150°C/W
CerDIP θ_{J-C} ..... 55°C/W
PDIP θ_{J-A} ..... 125°C/W
PDIP θ_{J-C} ..... 45°C/W
SOIC θ_{J-A} ..... 250°C/W
SOIC θ_{J-C} ..... 75°C/W

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Ordering Information

Part Number	Logic	Package	Temperature Range
MIC4604AJ	Inverting	8-pin CerDIP	–55°C to +125°C
MIC4604BM	Inverting	8-pin SOIC	–40°C to +85°C
MIC4604BN	Inverting	8-pin PDIP	–40°C to +85°C
MIC4605AJ	Non-Inverting	8-pin CerDIP	–55°C to +125°C
MIC4605BM	Non-Inverting	8-pin SOIC	–40°C to +85°C
MIC4605BN	Non-Inverting	8-pin PDIP	–40°C to +85°C

Note 1: Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specification is not implied. Exposure to Absolute Maximum Rating Conditions for extended periods may affect device reliability. Static-sensitive device. Unused devices must be stored in conductive material. Protect devices from static discharge and static fields.

Electrical Characteristics

Unless otherwise specified, specifications measured at $T_A = 25°C$ with $4.5V \le V_{DD} \le 18V$.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
Input						
V_{IH}	Logic 1 High Input Voltage		2.4		V_{DD} + 0.3	V
V_{IL}	Logic 0 Low Input Voltage		–5		0.8	V
I_{IN}	Input Current	$0V \le V_{IN} \le V_{DD}$	–1		1	µA
Output						
V_{OH}	High Output Voltage		V_{DD} – 0.025			V
V_{OL}	Low Output Voltage				0.025	V
R_O	Output Resistance, Pull-Up	I_{OUT} = 10mA, V_{DD} = 18V		6	10	Ω
R_O	Output Resistance, Pull-Down	I_{OUT} = 10mA, V_{DD} = 18V		6	10	Ω
I_{PK}	Peak Output Current	Any Drain		1.5		A
I_R	Latch-up Protection	Any Drain Reverse Current	>500			mA
Switching Time						
t_R	Rise Time	Figure 1, C_L = 1000pF		18	30	ns
t_F	Fall Time	Figure 1, C_L = 1000pF		27	35	ns
t_{D1}	Delay Time	Figure 1, C_L = 1000pF		17	30	ns
t_{D2}	Delay Time	Figure 1, C_L = 1000pF		23	50	ns
Power Supply						
I_S	Power Supply Current	V_{IN} = 3V (both inputs)		1.4	2.5	mA
		V_{IN} = 0V (both inputs)		0.18	0.25	mA

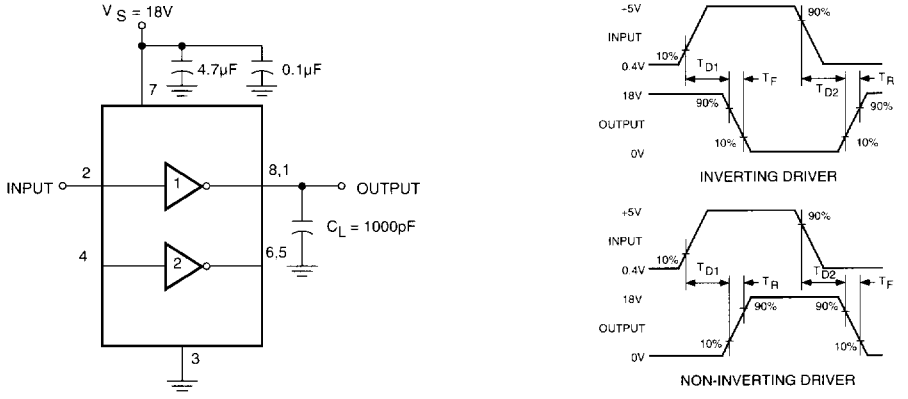

Figure 1. MIC4604/4605 Switching time test circuit.

Electrical Characteristics, continued

Specifications measured **over operating temperature range** with $4.5V \leq V_{DD} \leq 18V$, unless otherwise specified.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
Input						
V_{IH}	Logic 1 High Input Voltage		2.4		$V_{DD} + 0.3$	V
V_{IL}	Logic 0 Low Input Voltage				0.8	V
I_{IN}	Input Current	$0V \leq V_{IN} \leq V_{DD}$	–10		10	µA
Output						
V_{OH}	High Output Voltage		$V_{DD} - 0.025$			V
V_{OL}	Low Output Voltage				0.025	V
R_O	Output Resistance, Pull-Up	$I_{OUT} = 10mA$, $V_{DD} = 18V$		8	12	Ω
R_O	Output Resistance, Pull-Down	$I_{OUT} = 10mA$, $V_{DD} = 18V$		9	12	Ω
I_{PK}	Peak Output Current	Any Drain		1.5		A
I_R	Latch-up Protection	Any Drain Reverse Current	>500			mA
Switching Time						
t_R	Rise Time	Figure 1, $C_L = 1000pF$		20	40	ns
t_F	Fall Time	Figure 1, $C_L = 1000pF$		30	40	ns
t_{D1}	Delay Time	Figure 1, $C_L = 1000pF$		20	40	ns
t_{D2}	Delay Time	Figure 1, $C_L = 1000pF$		30	60	ns
Power Supply						
I_S	Power Supply Current	$V_{IN} = 3V$ (both inputs)		1.5	3.5	mA
		$V_{IN} = 0V$ (both inputs)		0.2	0.3	mA

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